

## SN74LV11A-Q1 汽车类三路 3 输入正与非门

### 1 特性

- 符合汽车应用要求
- 工作范围为 2V 至 5.5V  $V_{CC}$
- $V_{OLP}$  (输出接地反弹) 典型值小于 0.8V ( $V_{CC} = 3.3V$ ,  $T_A = 25^\circ C$ )
- $V_{OHV}$  (输出  $V_{OH}$  下冲) 典型值大于 2.3V ( $V_{CC} = 3.3V$ ,  $T_A = 25^\circ C$  时)
- 所有端口上均支持以混合模式电压运行
- $I_{off}$  支持局部关断模式运行

### 2 说明

这些三路 3 输入正与非门可在 2V 至 5.5V  $V_{CC}$  电压下运行。

**SN74LV11A-Q1** 器件以正逻辑执行布尔函数  $Y = A \cdot B \cdot C$  or  $Y = \overline{A + B + C}$ 。

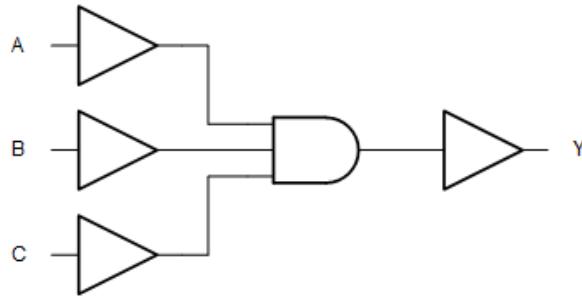
这些器件专用于使用  $I_{off}$  的局部断电应用。 $I_{off}$  电路禁用输出，从而可防止其断电时破坏性电流从该器件回流。

#### 封装信息

器件型号	封装 <sup>1</sup>	封装尺寸 <sup>2</sup>
SN74LV11A-Q1	PW ( TSSOP , 14 )	5.00 mm x 6.4 mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸 (长 x 宽) 为标称值，并包括引脚 (如适用)。



简化原理图



本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。有关适用的官方英文版本的最新信息，请访问 [www.ti.com](http://www.ti.com)，其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前，请务必参考最新版本的英文版本。

English Data Sheet: [SCES468](#)

## Table of Contents

1 特性.....	1	5.10 Operating Characteristics.....	6
2 说明.....	1	6 Parameter Measurement Information.....	7
3 Revision History.....	2	7 Detailed Description.....	8
4 Pin Configuration and Functions.....	3	7.1 Overview.....	8
5 Specifications.....	4	7.2 Functional Block Diagram.....	8
5.1 Absolute Maximum Ratings.....	4	7.3 Device Functional Modes.....	8
5.2 ESD Ratings.....	4	8 Device and Documentation Support.....	9
5.3 Recommended Operating Conditions .....	4	8.1 Documentation Support (Analog).....	9
5.4 Thermal Information.....	5	8.2 接收文档更新通知.....	9
5.5 Electrical Characteristics.....	5	8.3 支持资源.....	9
5.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ .....	5	8.4 Trademarks.....	9
5.7 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ .....	5	8.5 静电放电警告.....	9
5.8 Switching Characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ .....	6	8.6 术语表.....	9
5.9 Noise Characteristics.....	6	9 Mechanical, Packaging, and Orderable Information....	9

## 3 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (May 2023) to Revision E (July 2023)	Page
• 添加了封装信息表、引脚功能表、ESD 等级表、热信息表、器件功能模式、器件和文档支持部分以及机械、封装和可订购信息部分.....	1

## 4 Pin Configuration and Functions

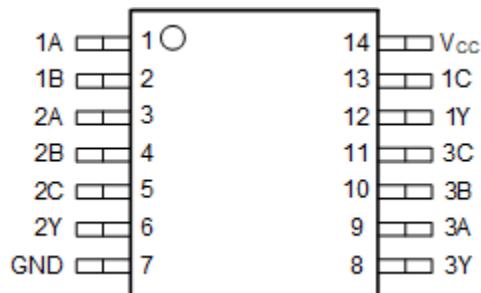


图 4-1. SN74LV11A-Q1 PW Package (Top View)

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
1A	1	I	1A Input
1B	2	I	1B Input
2A	3	I	2A Input
2B	4	I	2B Input
2C	5	I	2C Input
2Y	6	O	2Y Output
3Y	8	O	3Y Output
3A	9	I	3A Input
3B	10	I	3B Input
3C	11	I	3C Input
1Y	12	O	1Y Output
1C	13	I	1C Input
GND	7	—	Ground Pin
V <sub>cc</sub>	14	—	Power Pin

(1) Signal Types: I = Input, O = Output.

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	- 0.5	7	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	- 0.5	7	V
V <sub>O</sub>	Output voltage range applied in high or low state <sup>(2) (3)</sup>	- 0.5	V <sub>CC</sub> + 0.5	V
V <sub>O</sub>	Output voltage range applied in power-off state <sup>(2)</sup>	- 0.5	7	V
I <sub>IK</sub>	Input clamp current (V <sub>I</sub> < 0)		- 20	mA
I <sub>OK</sub>	Output clamp current (V <sub>O</sub> < 0)		- 50	mA
I <sub>O</sub>	Continuous output current (V <sub>O</sub> = 0 to V <sub>CC</sub> )		±25	mA
	Continuous current through V <sub>CC</sub> or GND		±50	mA
T <sub>stg</sub>	Storage temperature	- 65	150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 5.5 V maximum.

### 5.2 ESD Ratings

		VALUE	UNIT	
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	± 2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	2	5.5	V
V <sub>IH</sub>	High level input voltage	V <sub>CC</sub> = 2 V	1.5	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7	
		V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> × 0.7	
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.7	
V <sub>IL</sub>	Low level input voltage	V <sub>CC</sub> = 2 V	0.5	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.3	
		V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> × 0.3	
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.3	
V <sub>I</sub>	Input voltage	0	5.5	V
V <sub>O</sub>	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High level output current	V <sub>CC</sub> = 2 V	- 50	μA
		V <sub>CC</sub> = 2.3 V to 2.7 V	- 2	
		V <sub>CC</sub> = 3 V to 3.6 V	- 6	
		V <sub>CC</sub> = 4.5 V to 5.5 V	- 12	
I <sub>OL</sub>	Low level output current	V <sub>CC</sub> = 2 V	50	mA
		V <sub>CC</sub> = 2.3 V to 2.7 V	2	
		V <sub>CC</sub> = 3 V to 3.6 V	6	
		V <sub>CC</sub> = 4.5 V to 5.5 V	12	

### 5.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
$\Delta t/\Delta v$	Input transition rise and fall rate	$V_{CC} = 2.3\text{ V to }2.7\text{ V}$		200	ns/V
		$V_{CC} = 3\text{ V to }3.6\text{ V}$		100	
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$		20	
$T_A$	Operating free-air temperature		-40	105	°C

- (1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#)

### 5.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		SN74LV11A-Q1	UNIT
		PW	
		14 PINS	
$R_{JA}$ Junction-to-ambient thermal resistance		113	°C/W

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report ([SPRA953](#)).

### 5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CC}$	MIN	TYP	MAX	UNIT
$V_{OH}$ High-level output voltage	$I_{OH} = -50\text{ }\mu\text{A}$	2 V to 5.5 V	$V_{CC} - 0.1$			V
	$I_{OH} = -2\text{ mA}$	2.3 V	2			
	$I_{OH} = -6\text{ mA}$	3 V	2.48			
	$I_{OH} = -12\text{ mA}$	4.5 V	3.8			
$V_{OL}$ Low-level output voltage	$I_{OL} = 50\text{ }\mu\text{A}$	2 V to 5.5 V			0.1	V
	$I_{OL} = 2\text{ mA}$	2.3 V			0.4	
	$I_{OL} = 6\text{ mA}$	3 V			0.44	
	$I_{OL} = 12\text{ mA}$	4.5 V			0.55	
$I_I$	Input leakage current	$V_I = 5.5\text{ V or GND}$	0 to 5.5 V		$\pm 1$	μA
$I_{CC}$	Supply current	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		20	μA
$I_{off}$	Off-state leakage current	$V_I$ or $V_O = 0$ to 5.5 V	0 V		5	μA
$C_i$	Input capacitance	$V_I = V_{CC}$ or GND	3.3 V		1.9	pF

### 5.6 Switching Characteristics, $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			UNIT	
				MIN	TYP	MAX		
$t_{pd}$	A, B, or C	Y	$C_L = 50\text{ pF}$	9.9	17.5	1	21	ns

### 5.7 Switching Characteristics, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			UNIT	
				MIN	TYP	MAX		
$t_{pd}$	A, B, or C	Y	$C_L = 50\text{ pF}$	7.2	12.3	1	14	ns

## 5.8 Switching Characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN74LV11A-Q1	UNIT
				MIN	TYP	MAX		
$t_{pd}$	A, B, or C	Y	$C_L = 50 \text{ pF}$	5.4	7.9	1	9	ns

## 5.9 Noise Characteristics

$V_{CC} = 3.3 \text{ V}$ ,  $C_L = 50 \text{ pF}$ ,  $T_A = 25^\circ\text{C}$ <sup>(1)</sup>

PARAMETER	MIN	TYP	MAX	UNIT
$V_{OL(P)}$ Quiet output, maximum dynamic $V_{OL}$	0.2	0.8	0.8	V
$V_{OL(V)}$ Quiet output, minimum dynamic $V_{OL}$	0	-0.8	-0.8	V
$V_{OH(V)}$ Quiet output, minimum dynamic $V_{OH}$	3.2			V
$V_{IH(D)}$ High-level dynamic input voltage	2.31			V
$V_{IL(D)}$ Low-level dynamic input voltage	0.99			V

(1) Characteristics are for surface-mount packages only.

## 5.10 Operating Characteristics

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	$V_{CC}$	TYP	UNIT
$C_{pd}$ Power dissipation capacitance	$C_L = 50 \text{ pF}$ , $f = 10 \text{ MHz}$	3.3 V	13.9	pF
		5 V	15.4	

## 6 Parameter Measurement Information

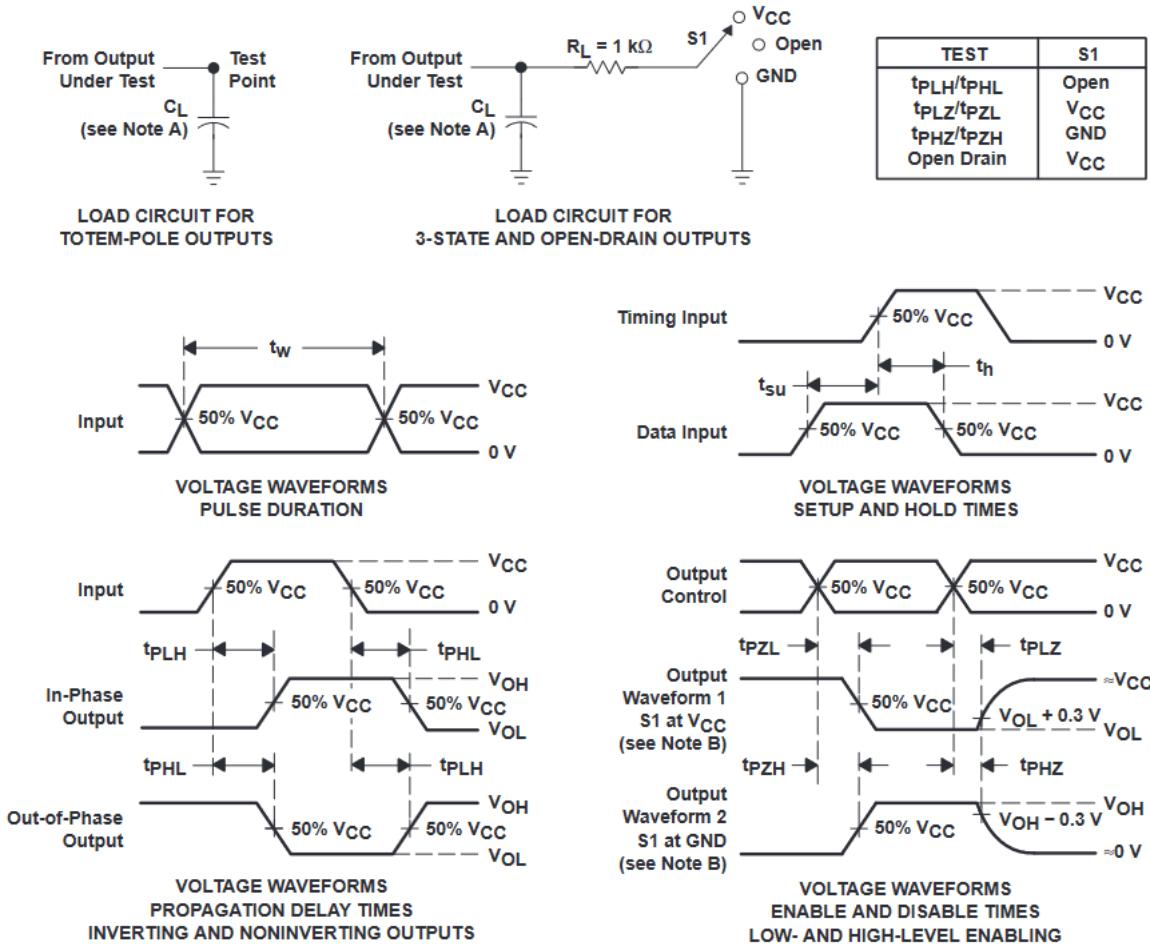


图 6-1. Load Circuit and Voltage Waveforms

- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq 1$  MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

## 7 Detailed Description

### 7.1 Overview

These triple 3-input positive-AND gate is designed for 2-V to 5.5-V  $V_{CC}$  operation. The SN74LV11A-Q1 device performs the Boolean function  $Y = A + B + \overline{C}$  in positive logic. This devices is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### 7.2 Functional Block Diagram

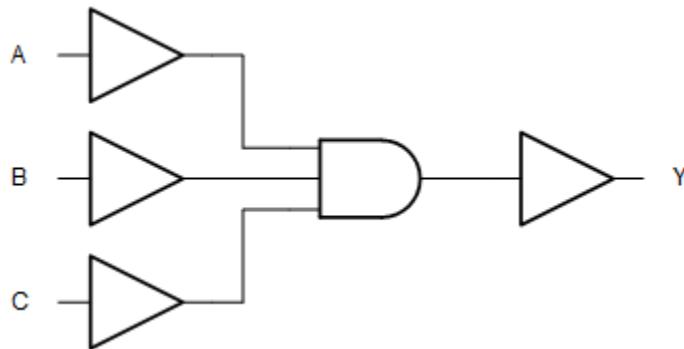


图 7-1. logic diagram, each gate (positive logic)

### 7.3 Device Functional Modes

表 7-1. FUNCTION TABLE  
(each gate)

INPUT <sup>(1)</sup>			OUTPUT <sup>(2)</sup>
A	B	C	Y
H	H	H	H
L	X	X	L
X	L	X	L
X	X	L	L

(1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care

(2) H = Driving High, L = Driving Low

## 8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 8.1 Documentation Support (Analog)

#### 8.1.1 Related Documentation

表 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LV11A-Q1	<a href="#">Click here</a>				

### 8.2 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](http://ti.com) 上的器件产品文件夹。点击[订阅更新](#)进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

### 8.3 支持资源

[TI E2E™ 支持论坛](#)是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的[《使用条款》](#)。

### 8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

### 8.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 8.6 术语表

#### TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

## 9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV11ATPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	LV11AT	<span style="background-color: red; color: white;">Samples</span>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

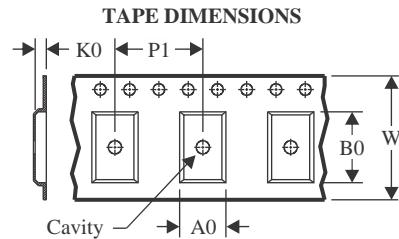
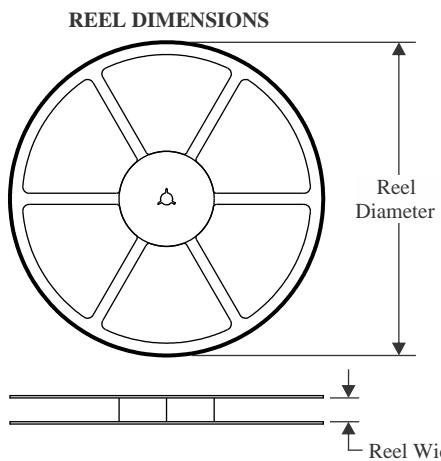
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF SN74LV11A-Q1 :**

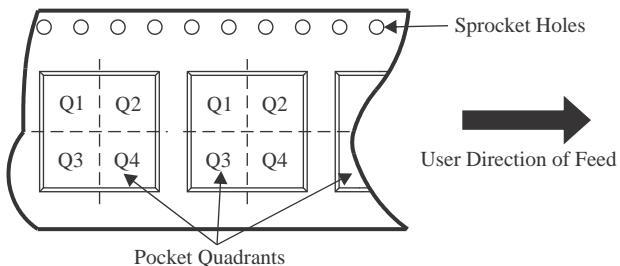
- Catalog : [SN74LV11A](#)
- Enhanced Product : [SN74LV11A-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

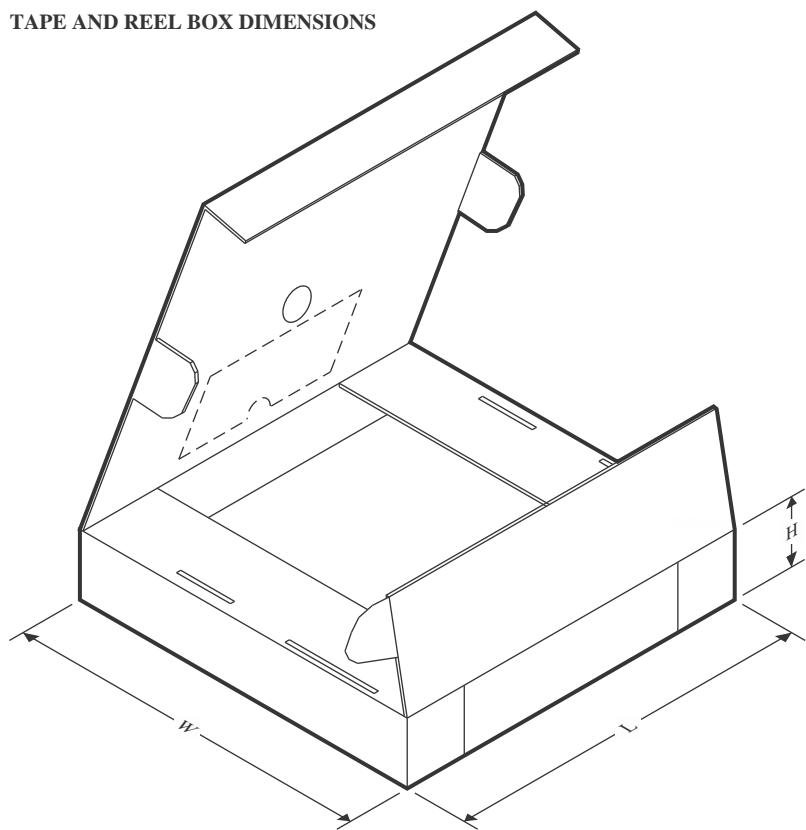
**TAPE AND REEL INFORMATION**

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV11ATPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV11ATPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

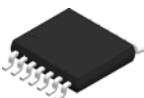
**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV11ATPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LV11ATPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0

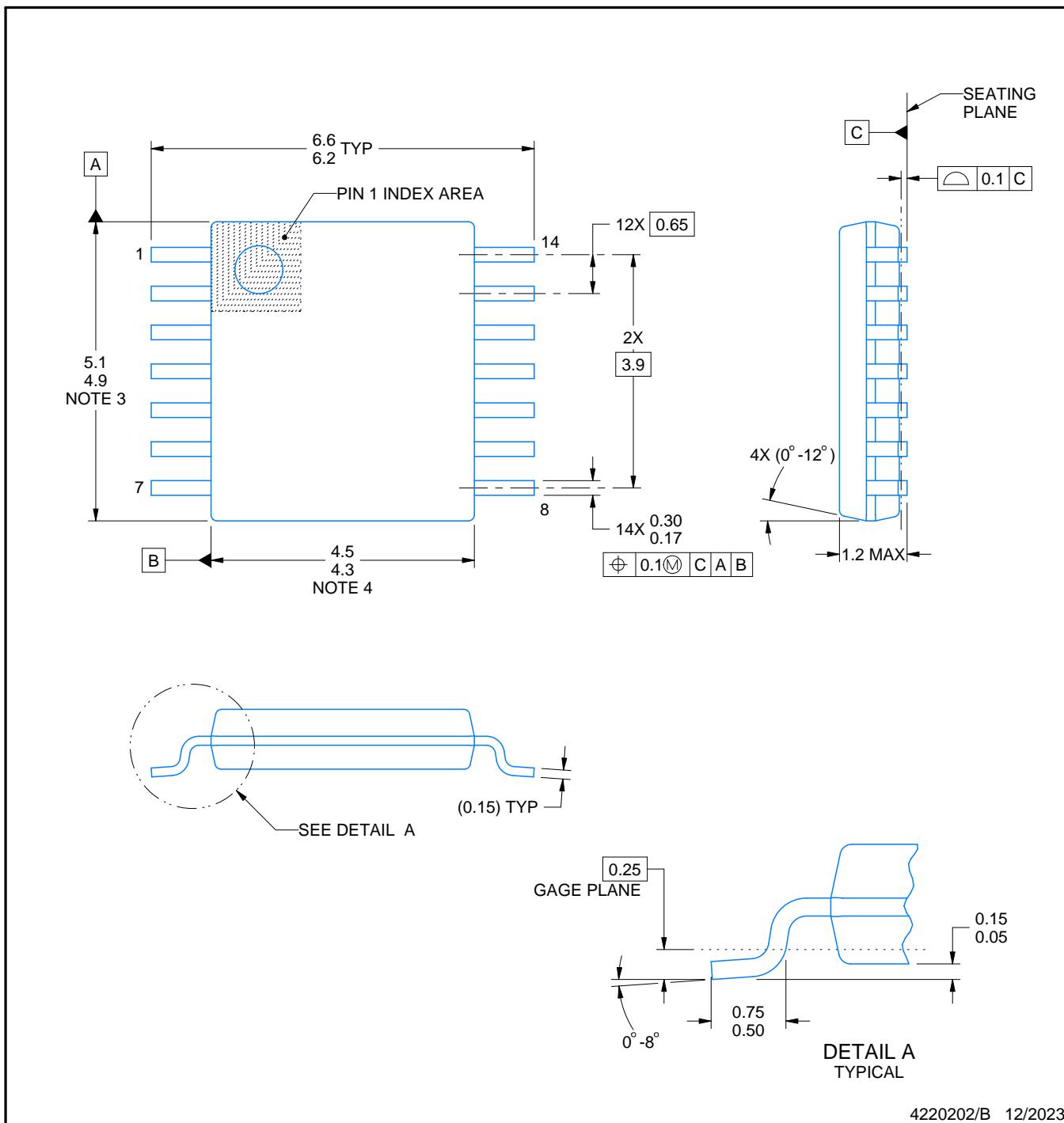
# PACKAGE OUTLINE

PW0014A



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

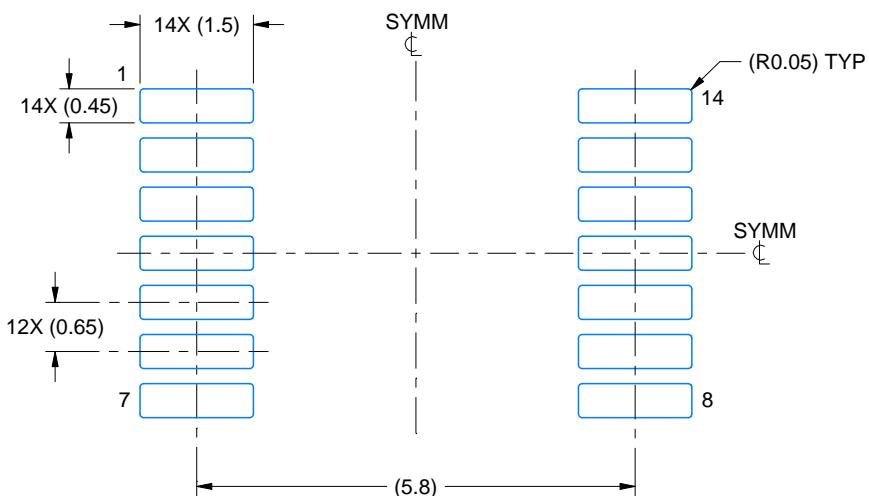
- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

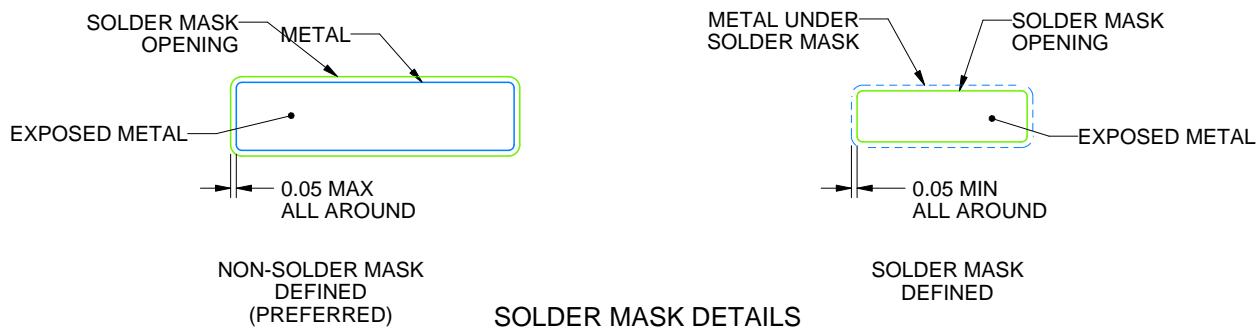
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

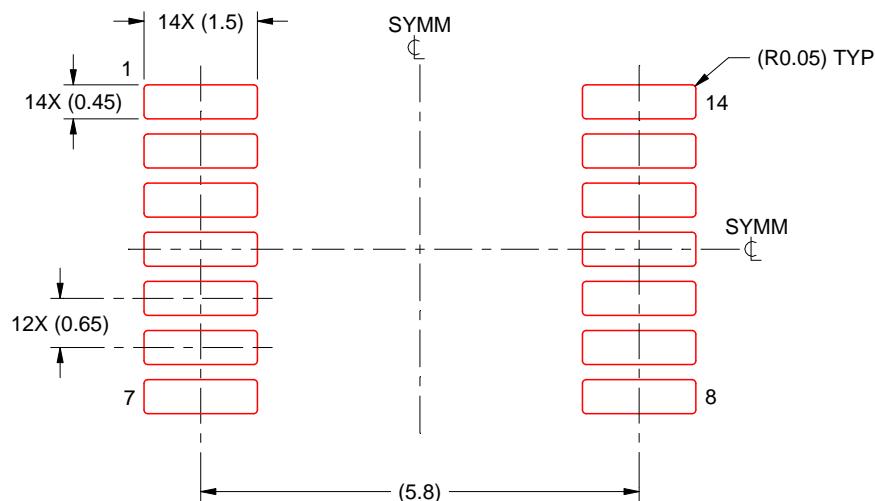
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## 重要声明和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做出任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址 : Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2024, 德州仪器 (TI) 公司